



20V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26

Features

- $BV_{CEO} > -20V$
- I_C = -2.5A Continuous Collector Current
- I_{CM} = -6A Peak Pulse Current
- $R_{CE(sat)} = 96m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage (-220mV max @ 1A)
- hFE Characterized up to -6A for High Current Gain Hold-Up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

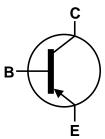
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202. Method 208 @3
- Weight: 0.015 grams (Approximate)

Applications

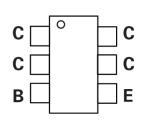
- DC-DC Converters
- **Power Management Functions**
- **Power Switches**
- Motor Control







Device Symbol



Pin-Out Top

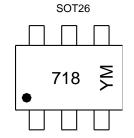
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT10P20DE6TA	718	7	8	3,000
ZXT10P20DE6TC	718	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



718 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	201	5	2016	2017	2018	2019	2020	202	1 20)22 2	2023	2024	2025
Code	С		D	Е	F	G	Н	1		J	K	L	M
Month	h	Jaı	n Fel	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code		1	2	3	4	5	6	7	8	9	0	N	D

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Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-20	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Base Voltage	V _{EBO}	-7	V
Base Current	I _B	-500	mA
Continuous Collector Current	Ic	-2.5	А
Peak Pulse Collector Current	I _{CM}	-6	А

Thermal Characteristics ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	В	1.1 8.8	W
Linear Derating Factor	(Note 6)	P _D	1.7 13.6	mW/°C
Thermal Resistance, Junction to Ambient	(Note 5)	D	113	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{θJA}	73	C/VV
Thermal Resistance, Junction to Leads	$R_{ heta JL}$	30.01	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

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- 6. Same as Note 5, except the device is measured at t ≤ 5secs.

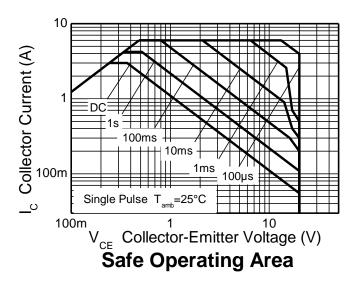
 7. Thermal resistance from junction to solder-point (at the end of the collector leads).

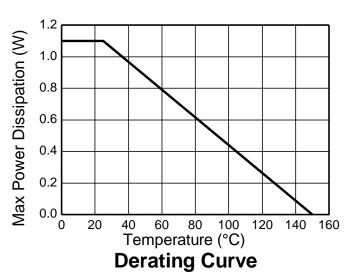
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

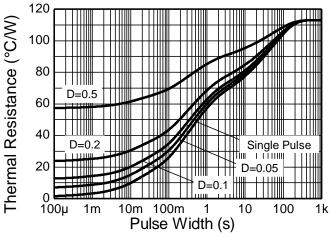




Thermal Characteristics and Derating Information







Transient Thermal Impedance





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

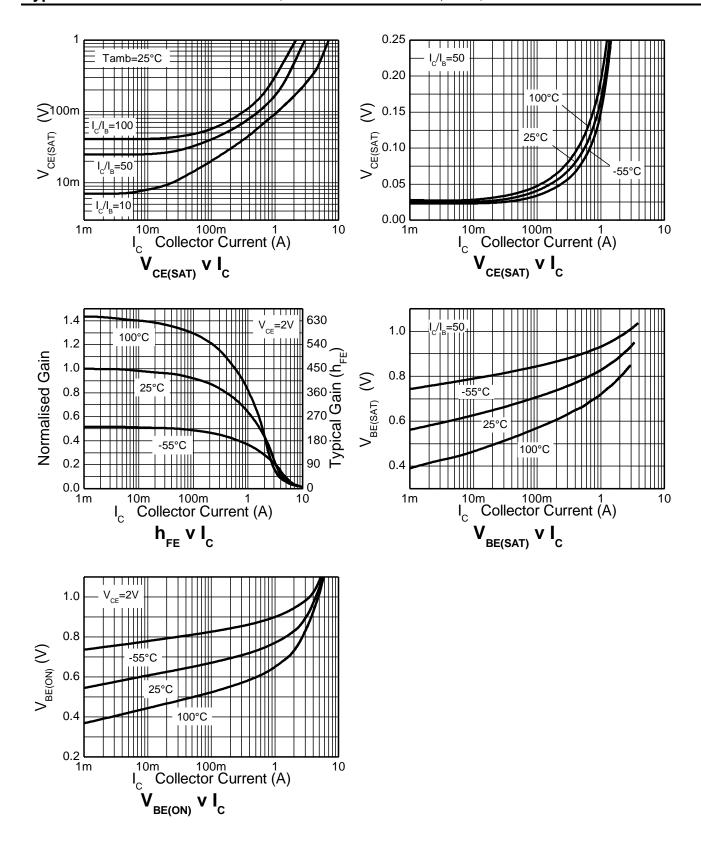
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	-20	-65	_	V	$I_{C} = -100\mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-20	-53		V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8.8	_	V	$I_E = -100 \mu A$
Collector-Base Cutoff Current	I _{CBO}	_	<1	-100	nA	V _{CB} = -15V
Emitter Cutoff Current	I _{EBO}	_	<1	-100	nA	V _{EB} = -5V
Collector-Emitter Cutoff Current	I _{CES}	_	<1	-100	nA	V _{CES} = -15V
ON CHARACTERISTICS (Note 9)						
		300	475	_	_	$I_C = -10 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Gain	h _{FE}	300	450		_	$I_C = -0.1A$, $V_{CE} = -2V$
DC Current Gain		150	230	_	_	$I_C = -2A$, $V_{CE} = -2V$
		15	30	_	_	$I_C = -6A$, $V_{CE} = -2V$
		_	-19	-30	mV	I _C = -0.1A, I _B = -10mA
Collector-Emitter Saturation Voltage	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	_	-170	-220		I _C = -1A, I _B = -20mA
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	-190	-250	IIIV	$I_C = -1.5A$, $I_B = -50mA$
		_	-240	-350		I _C = -2.5A, I _B = -150mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	-0.97	-1.05	V	I _C = -2.5A, I _B = -150mA
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	-0.85	-0.95	V	I _C = -2.5A, V _{CE} = -2V
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f_{T}	150	180	_	MHz	$V_{CE} = -10V$, $I_{C} = -50mA$, $f = 100MHz$
Output Capacitance	C _{obo}	_	21	30	pF	V _{CB} = -10V, f = 1MHz
Turn-On Time	t _(on)		40		ns	V _{CC} = -10V, I _C = -1A
Turn-Off Time	t _(Off)	_	670	_	ns	$I_{B1} = -I_{B2} = -20\text{mA}$

Note: 9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s.$ Duty cycle $\leq 2\%.$





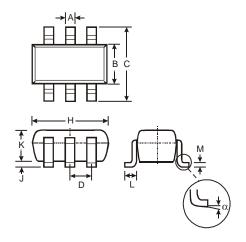
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

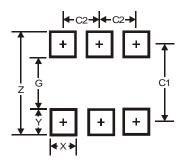
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT26							
Dim	Min	Max	Тур					
Α	0.35	0.50	0.38					
В	1.50	1.70	1.60					
С	2.70	3.00	2.80					
D	_	_	0.95					
Н	2.90	3.10	3.00					
J	0.013	0.10	0.05					
K	1.00	1.30	1.10					
L	0.35	0.55	0.40					
M	0.10	0.20	0.15					
α	0°	8°						
All D	All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Υ	0.80
C1	2.40
C2	0.95





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